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Physics, Simulation, and Photonic Engineering of Photovoltaic Devices VIII

**Alexandre Freundlich
Laurent Lombez
Masakazu Sugiyama**
Editors

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Contents

vii	<i>Authors</i>
ix	<i>Conference Committee</i>

ADVANCED PHOTOVOLTAIC CHARACTERIZATION I

10913 07	Buried interface and luminescent coupling analysis with time-resolved two-photon excitation microscopy in II-VI and III-V semiconductor heterostructures (Invited Paper) [10913-6]
10913 08	Temperature and excitation dependence of recombination in CIGS thin films with high spatial resolution [10913-7]
10913 0A	Simulation of photon transport in resonant double-diode structures [10913-9]

HOT CARRIER SOLAR CELLS I

10913 0D	Light absorption enhancement in ultra-thin layers for hot-carrier solar cells: first developments towards the experimental demonstration of an enhanced hot-carrier effect with light trapping [10913-12]
----------	--

HOT CARRIER SOLAR CELLS II

10913 0G	Slowed hot carrier cooling in multiple quantum wells for application to hot carrier solar cells (Invited Paper) [10913-15]
10913 0H	Unusual hot carrier effect and improved carrier extraction observed in asymmetric dilute-nitride quantum-engineered solar cells through photoluminescence (PL) and external quantum efficiency (EQE) measurements [10913-16]

EMERGING LIGHT MANAGEMENT AND PHOTONIC ENGINEERING IN PV DEVICES

10913 0K	Efficient multiphysics modeling of thin-film solar cells with periodically textured surfaces [10913-19]
10913 0L	Tunable prism based upon novel piezoelectric nanoparticle/sol-gel design used for active solar cells concentrators [10913-20]
10913 0M	Optimized solar cells based on changes in resonance structure as a function of the refractive index and the thickness [10913-21]

ADVANCES FOR SILICON-BASED PHOTOVOLTAIC MATERIALS AND DEVICES

- 10913 OT **A porous Ge/Si interface layer for defect-free III-V multi-junction solar cells on silicon**
[10913-28]
- 10913 OU **Black silicon (BS) using room-temperature reactive ion etching (RT-RIE) for interdigitated back contact (IBC) silicon solar cells** [10913-29]

ADVANCED PHOTOVOLTAIC CHARACTERIZATION II

- 10913 OY **Monitoring carrier transport and recombination in photovoltaic devices in real time** [10913-33]
- 10913 OZ **Numerical simulations of cathodoluminescence measurements in thin-film solar cells**
[10913-34]

NANO AND QUANTUM ENGINEERED PHOTOVOLTAIC DEVICES

- 10913 10 **Effective mobility map for InGaP/InGaP multiple quantum-well-based solar cells** [10913-35]
- 10913 12 **Effect of capping rate on InAs/GaAs quantum dot solar cells** [10913-37]
- 10913 14 **III-V dilute nitride quantum-engineered solar cell for lattice-matched silicon-based tandems**
[10913-39]

EMERGING PHOTOVOLTAIC DEVICE CONCEPTS

- 10913 16 **A concept of nonequilibrium solar cell heat recovery solar cell** [10913-41]
- 10913 17 **Investigation of narrow bandgap interband cascade thermophotovoltaic cells** [10913-42]
- 10913 18 **Integrated electrochemical energy storage and photovoltaic device with a gel electrolyte**
[10913-43]

POSTER SESSION

- 10913 1A **Nearly polarization-independent absorber consisting of metal-insulator multilayer stacks loaded with a metal patch** [10913-46]
- 10913 1E **Characteristics of asymmetrical tapered nano-cone solar cell** [10913-50]
- 10913 1G **Characteristics of modified nanopyramid silicon solar cell** [10913-52]

- 10913 1I **A new method for estimating photometric and colorimetric properties using RGB sensor and ANN [10913-54]**
- 10913 1J **Numerical estimation of solar resource for curved panels on Earth and Mars [10913-55]**
- 10913 1K **Optimal geometry of solar cells with genetics algorithm [10913-56]**
- 10913 1N **Multiscale device simulation of quantum dot solar cells [10913-59]**
- 10913 1O **Chaos: a new mechanism for enhancing the optical generation rate in optically thin solar cells [10913-60]**
- 10913 1P **Enhanced performance of InGaN thin-film solar cells containing plasmonic and dielectric nanostructures [10913-61]**

Authors

Numbers in the index correspond to the last two digits of the seven-digit citation identifier (CID) article numbering system used in Proceedings of SPIE. The first five digits reflect the volume number. Base 36 numbering is employed for the last two digits and indicates the order of articles within the volume. Numbers start with 00, 01, 02, 03, 04, 05, 06, 07, 08, 09, 0A, 0B...0Z, followed by 10-1Z, 20-2Z, etc.

Ahmed, Kaleem, 1P	Ito, Hiroshi, 1A
Akiyama, Hidefumi, 0Y, 16	Jehl, Zacharie, 0D
Aljafari, Belqasem, 18	Jelinek, Raz, 0L
Al-Jassim, Mowafak, 08, 0Z	Jellit, Mourad, 0T
Arès, Richard, 0T	Kamide, Kenji, 16
Atteia, F., 0U	Khalili, Arastoo, 1N
Barcellos, Robson, 1I	Kharel, Khim, 0H, 14
Beattie, Meghan N., 0T	Kim, C., 0Y
Berginc, G., 0U	Kivisaari, Pyry, 0A
Bhardwaj, Priyanka, 1P	Kohler, Achim, 0M, 1O
Bloud, Youcef A., 0T	Kuciauskas, Darius, 07
Blümel, Reinhold, 0M, 1O	Kumar, Kamal, 1P
Boucherif, Abderraouf, 0T	Kumawat, Uttam K., 1P
Braidy, Nadi, 0T	Le Rouzo, J., 0U
Brandsrud, Maren Anna, 0M, 1O	Li, Lu, 17
Braza, V., 12	Lincoln, Victor A. C., 1I
Bremner, Stephen, 0G	Lombes, Laurent, 0D
Cappelluti, Federica, 0K, 1N	Lukacs, Rozalia, 0M, 1O
Cattoni, Andrea, 0D	Mahmoud, Amr Hisham K., 1G
Cho, Edwin, 1J	Mahmoud, Korany R., 1E
Chowdhury, Rahul, 1K	Malik, Roger, 07
Cirino, Giuseppe A., 1I	Marciniak, Matgorzata, 1J, 1K
Collin, Stéphane, 0D	Martinez, Andrea, 1J
Conibeer, Gavin, 0G	Massengale, Jeremy A., 17
Das, Pankaj, 1P	Mello, Marcio M., 1I
Delamarre, Amaury, 0D, 10	Metzger, Wyatt K., 0Z
Dhawan, Anuj, 1P	Mishima, Tetsuya D., 17
Drouin, Dominique, 0T	Miyashita, Naoya, 0D
Dubajic, Milos, 0G	Mochizuki, Toshimitsu, 16
Ecoffey, Serge, 0T	Moseley, John, 08, 0Z
Elsehrawy, Farid, 0K, 1N	Nakano, Hisamatsu, 1A
Enriquez-Torres, Delfino, 1J	Nakano, Yoshiaki, 10
Escoubas, L., 0U	Nishinaga, Jiro, 08
Freundlich, Alexandre, 0H, 14	Obayya, S. S. A., 1E, 1G
Fuertes Marrón, D., 12	Okada, Yoshitaka, 0D
Giteau, Maxime, 0D	Oksanen, Jani, 0A
Goffard, Julie, 0D	Olsen, Espen, 0M, 1O
González, D., 12	Partanen, Mikko, 0A
Gonzalo, A., 12	Patriarche, Gilles, 0T
Guillemoles, Jean-François, 0D	Rachamim, Gilad, 0L
Guthrey, Harvey, 08, 0Z	Ram, Manoj K., 18
Hameed, Mohamed Farhat O., 1E, 1G	Reyes, D. F., 12
Hazama, Y., 0Y	Ritenberg, Margarita, 0L
Hierro, A., 12	Sadi, Toufik, 0A
Hinzer, Karin, 0T	Santos, Michael B., 17
Huang, Hsiang-Hung, 10	Schiabel, Homero, 1I
Huang, Wenxiang, 17	Seim, Eivind, 0M, 1O
Hussein, Mohamed, 1E, 1G	Shibata, Hajime, 08
Ishida, Y., 0Y	Shin, S., 0Y

Shrestha, Santosh, 0G
Simon, J. J., 0U
Sodabanlu, Hassanet, 0D
Soltani, Ali, 0T
Stanojević, L., 12
Steiner, Myles A., 07
Stensrud Marstein, Erik, 0M, 1O
Stricher, Romain, 0T
Suchet, Daniel, 0D
Sugiyama, Masakazu, 0D, 10
Sun, Justin Zenas, 10
Takahashi, Hideki, 08
Takahashi, Naoki, 1A
Takato, Hidetaka, 16
Takshi, Arash, 18
Tamaki, Ryo, 0D
Tayebjee, Murad, 0G
Tibaldi, Alberto, 0K, 1N
Toprasertpong, Kasidit, 10
Troadec, David, 0T
Ulloa, J. M., 12
Utrilla, A. D., 12
Valdivia, Christopher E., 0T
Ventura, Liliane, 1I
Watanabe, Kentaroh, 0D, 10
Wilkins, Matthew, 0T
Yamauchi, Junji, 1A
Yang, Rui Q., 17
Zalevsky, Zeev, 0L
Zhang, Yi, 0G
Zhu, L., 0Y

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- 1 Advances in Perovskites Materials and Devices
Laurent Lombez, Institut Photovoltaïque d'Ile-de-France (France)
Alexandre Freundlich, University of Houston (United States)
- 2 Advanced Photovoltaic Characterization I
Kentaroh Watanabe, The University of Tokyo (Japan)
Hugh W. Hillhouse, University of Washington (United States)
- 3 Hot Carrier Solar Cells I
Jean-François Guillemoles, Institut Photovoltaïque d'Ile-de-France (France)
Matthew C. Beard, National Renewable Energy Laboratory (United States)
- 4 Hot Carrier Solar Cells II
Ian R. Sellers, The University of Oklahoma (United States)
Jeremy N. Munday, University of Maryland, College Park (United States)
- 5 Emerging Light Management and Photonic Engineering in PV Devices
Kentaroh Watanabe, The University of Tokyo (Japan)
Gavin Conibeer, The University of New South Wales (Australia)
- 6 Advanced Nanoscale Photonic Engineering of Solar Cells
Karin Hinzer, University of Ottawa (Canada)
Seth M. Hubbard, Rochester Institute of Technology (United States)
- 7 Advances for Silicon-based Photovoltaic Materials and Devices
Alexandre Freundlich, University of Houston (United States)
Laurent Lombez, Institut Photovoltaïque d'Ile-de-France (France)
- 8 Advanced Photovoltaic Characterization II
Darius Kuciauskas, National Renewable Energy Laboratory (United States)
- 9 Nano and Quantum Engineered Photovoltaic Devices
Stéphane Collin, Centre de Nanosciences et de Nanotechnologies (France)
John Moseley, National Renewable Energy Laboratory (United States)
- 10 Emerging Photovoltaic Device Concepts
Mariana I. Bertoni, Arizona State University (United States)
Alexandre Freundlich, University of Houston (United States)